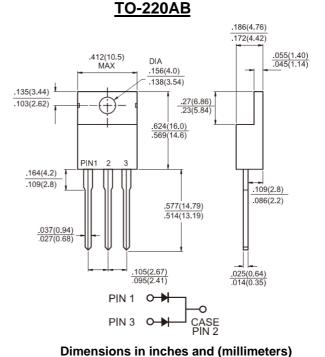


# **GP1001 - GP1007** 10.0 AMPS. Glass Passivated Rectifiers



## **Features**

- ♦ Glass passivated chip junction
- ♦ High efficiency, Low VF
- ♦ High current capability
- ♦ High reliability
- ♦ High surge current capability
- ♦ Low power loss
- Green compound with suffix "G" on packing code & prefix "G" on datecode



**Marking Diagram** 

= Year

GP100X = Specific Device Code

= Work Week

= Green Compound

0

SGYWW GP100X G

Y

WW

# Mechanical Data

- ♦ Cases: TO-220AB Molded plastic
- $\diamond\quad \text{Epoxy: UL 94V-0 rate flame retardant}$
- Lead: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- Polarity: As marked
- ↔ High temperature soldering guaranteed: 260°C/10 seconds .16", (4.06mm) from case.
- ♦ Weight: 2.24 grams

**Maximum Ratings and Electrical Characteristics** Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

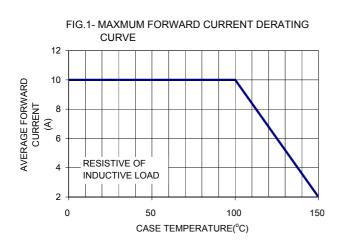
| Type Number   | Symbol                | GP<br>1001    | GP<br>1002 | GP<br>1003 | GP<br>1004 | GP<br>1005 | GP<br>1006 | GP<br>1007 | Units |
|---|-----------------------|---------------|------------|------------|------------|------------|------------|------------|-------|
| Maximum Recurrent Peak Reverse Voltage  | V <sub>RRM</sub>      | 50            | 100        | 200        | 400        | 600        | 800        | 1000       | V     |
| Maximum RMS Voltage   | V <sub>RMS</sub>      | 35            | 70         | 140        | 280        | 420        | 560        | 700        | V     |
| Maximum DC Blocking Voltage   | V <sub>DC</sub>       | 50            | 100        | 200        | 400        | 600        | 800        | 1000       | V     |
| Maximum Average Forward Rectified Current   | I <sub>F(AV)</sub>    | 10            |            |            |            |            |            |            | А     |
| Peak Forward Surge Current, 8.3 ms Single Half Sine-wave<br>Superimposed on Rated Load (JEDEC method) | I <sub>FSM</sub>      | 125           |            |            |            |            |            | А          |       |
| Maximum Instantaneous Forward Voltage (Note 1)<br>@ 5 A   | V <sub>F</sub>        | 1.1           |            |            |            |            |            |            | V     |
| Maximum DC Reverse Current at@ $T_A=25 \degree C$ Rated DC Blocking Voltage@ $T_A=125\degree C$       | I <sub>R</sub>        | 5<br>200      |            |            |            |            |            |            | uA    |
| Typical Junction Capacitance (Note 2)   | Cj                    | 30            |            |            |            |            |            |            | pF    |
| Typical Thermal Resistance  | $R_{	extsf{	heta}JC}$ | 3             |            |            |            |            |            |            | °C/W  |
| Operating and Storage Temperature Range   | $T_J, T_{STG}$        | - 65 to + 150 |            |            |            |            |            |            | °C    |

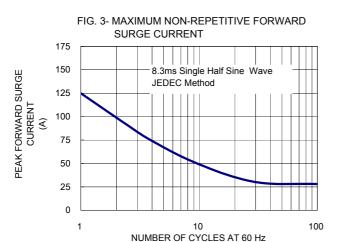
Note1: Pulse Test with PW=300 usec, 1% Duty Cycle

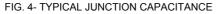
Note2: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

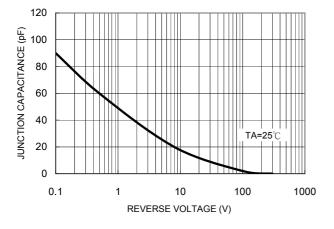


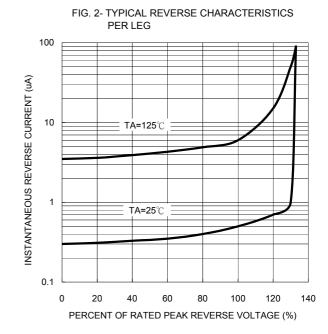
## RATINGS AND CHARACTERISTIC CURVES (GP1001 THRU GP1007)

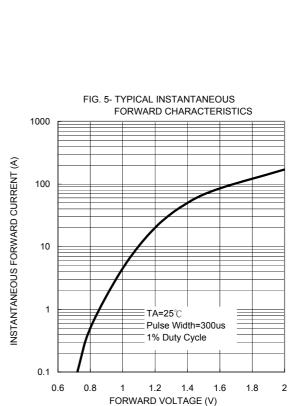












Version:E11